



# PJA3412

## 20V N-Channel Enhancement Mode MOSFET

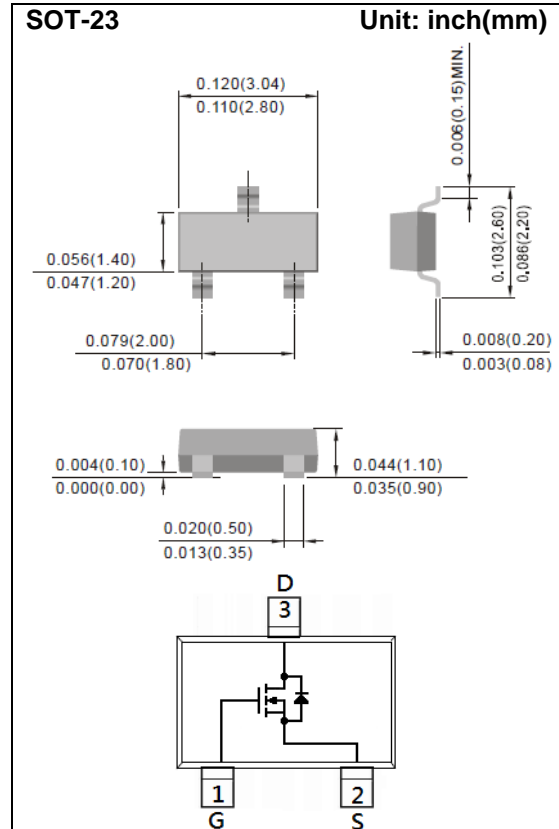
<b>Voltage</b>	<b>20 V</b>	<b>Current</b>	<b>4.1 A</b>
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### Features

- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@4.1A < 56m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_D@2.8A < 68m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@1.8V$ ,  $I_D@1.5A < 95m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

### Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	20	V
Gate-Source Voltage		$V_{GS}$	$\pm 12$	
Continuous Drain Current		$I_D$	4.1	A
Pulsed Drain Current		$I_{DM}$	16.4	
Power Dissipation	$T_a=25^\circ C$	$P_D$	1.25	W
	Derate above $25^\circ C$		10	mW/ $^\circ C$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ C$
Typical Thermal Resistance		$R_{\theta JA}$	100	$^\circ C/W$
- Junction to Ambient <sup>(Note 3)</sup>				



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.4	0.66	1.2	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=4.1A$	-	41	56	m $\Omega$
		$V_{GS}=2.5V, I_D=2.8A$	-	50	68	
		$V_{GS}=1.8V, I_D=1.5A$	-	66	95	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=4.1A,$ $V_{GS}=4.5V$ (Note 1,2)	-	4.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1	-	
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V,$ $f=1MHz$	-	350	-	pF
Output Capacitance	$C_{oss}$		-	40	-	
Reverse Transfer Capacitance	$C_{rss}$		-	29	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=4.1A,$ $V_{GS}=4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	4	-	ns
Turn-On Rise Time	$t_r$		-	47	-	
Turn-Off Delay Time	$t_{d(off)}$		-	18	-	
Turn-Off Fall Time	$t_f$		-	10	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	1.5	A
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$	-	0.75	1.2	V

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

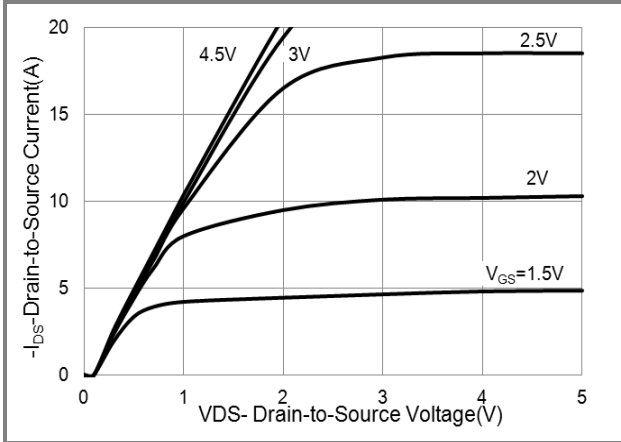


Fig.1 On-Region Characteristics

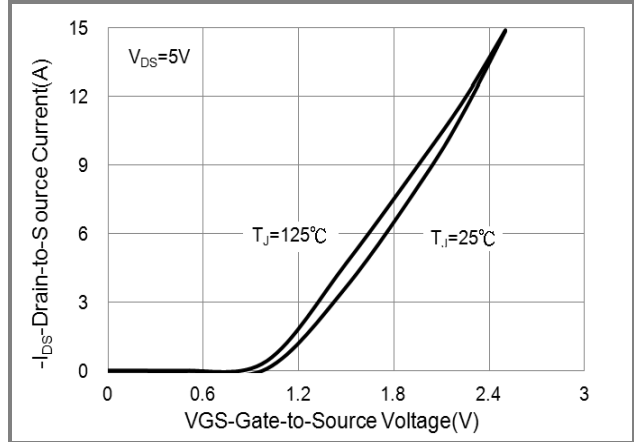


Fig.2 Transfer Characteristics

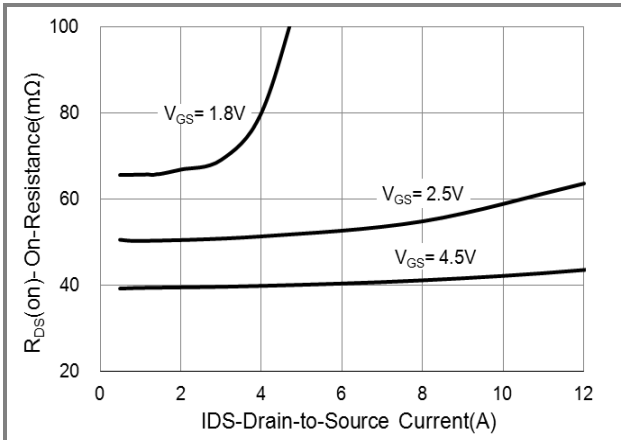


Fig.3 On-Resistance vs. Drain Current

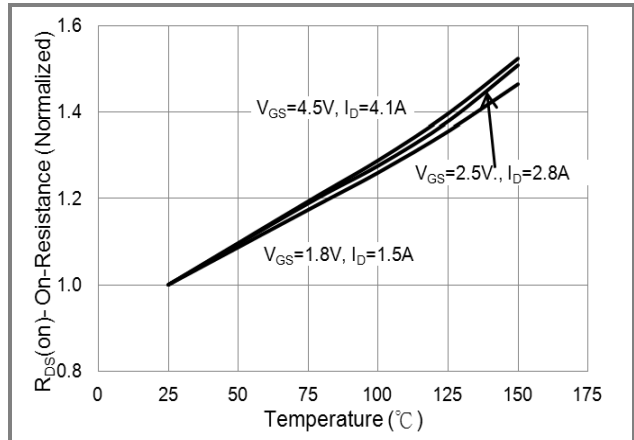


Fig.4 On-Resistance vs. Junction temperature

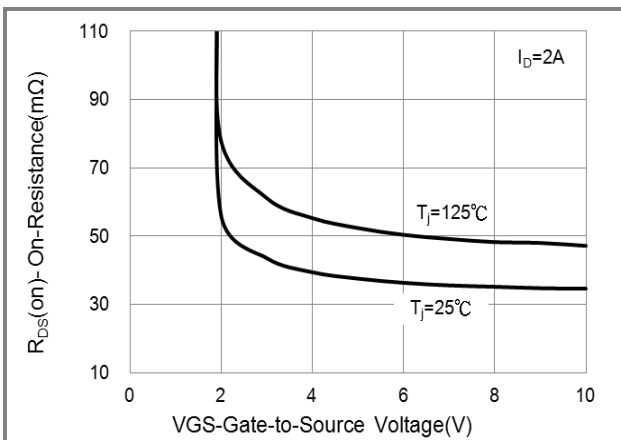


Fig.5 On-Resistance Variation with  $V_{GS}$

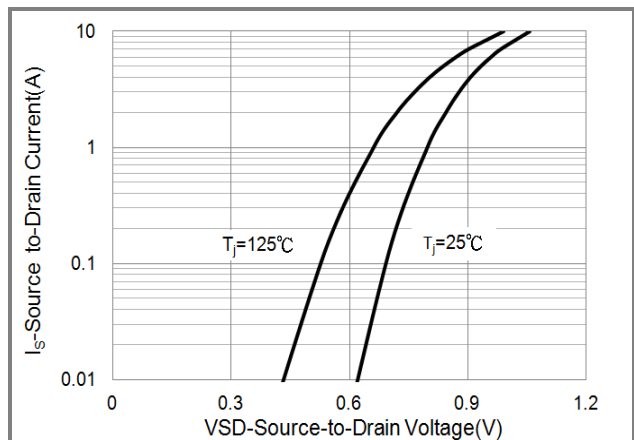


Fig.6 Body Diode Characteristics



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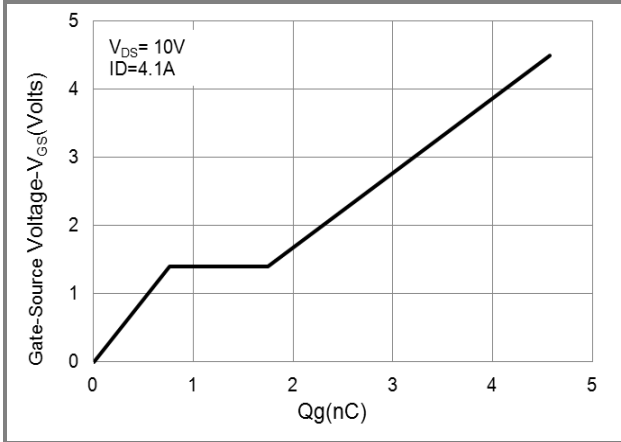


Fig.7 Gate-Charge Characteristics

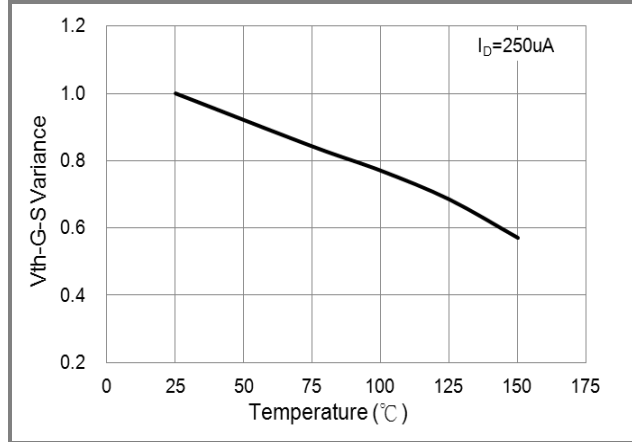


Fig.8 Threshold Voltage Variation with Temperature

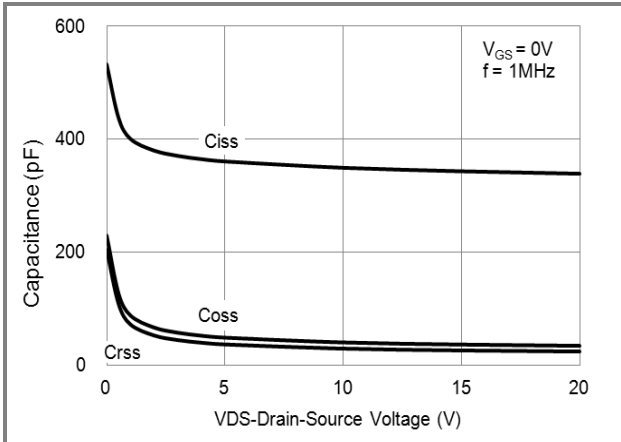


Fig.9 Capacitance vs. Drain-Source Voltage

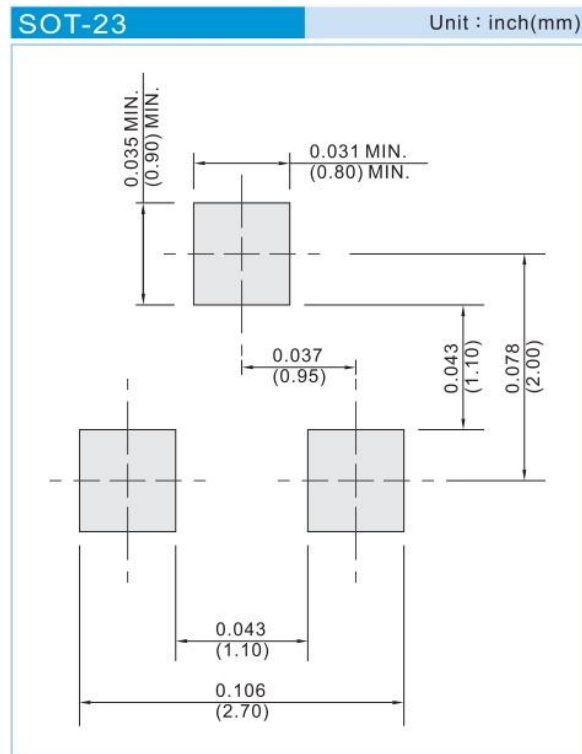


# PJA3412

## Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3412_R1_00001	SOT-23	3K pcs / 7" reel	A12	Halogen free

## Mounting Pad Layout





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